

PowerDI3333-8

#### **Product Summary**

BVDSS	RDS(ON) Max	I <sub>D</sub> Max (Note 10) Tc = +25°C
	3.0mΩ @ V <sub>GS</sub> = 10V	100A
40V	5.0mΩ @ V <sub>GS</sub> = 5V	93A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor controls
- DC-DC converters
- Power managements

#### **Features and Benefits**

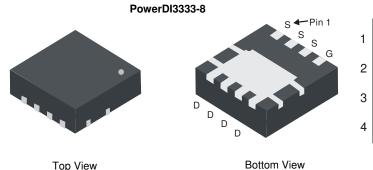
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching, Test in Production Ensures More Reliable and Robust End Application
- Low R<sub>DS(ON)</sub> Ensures On-State Losses are Minimized
- Excellent Q<sub>GD</sub> × R<sub>DS(ON)</sub> Product (FOM)
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH43M8LFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

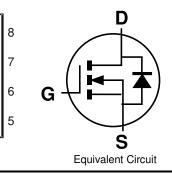
https://www.diodes.com/guality/product-definitions/

#### **Mechanical Data**

- Package: PowerDI<sup>®</sup>3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.034 grams (Approximate)

Top View





#### Ordering Information (Note 4)

Part Number	Bookago	Packing		
Part Number	Package	Qty.	Carrier	
DMTH43M8LFGQ-7	PowerDI3333-8	2,000	Tape & Reel	
DMTH43M8LFGQ-13	PowerDI3333-8	3,000	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

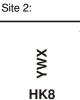
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# Marking Information

#### Site 1:



HK8 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 23 = 2023) WW = Week Code (01 to 53)



HK8 = Product Type Marking Code YWX = Date Code Marking Y = Year Code (ex: 3 = 2023) W = Week Code (ex: a = Week 27, z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)



#### Maximum Ratings (@Tc = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	40	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 7) (Note 10) $V_{GS}$ = 10V	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	lo	100 85	A
Continuous Drain Current (Note 6) $V_{GS} = 10V$	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	ID	24.0 16.9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		IDM	400	А
Maximum Continuous Body Diode Forward Current (Note 7) (	Note 10)	Is	100	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle	= 1%)	lsм	400	А
Avalanche Current, L = 1mH		I <sub>AS</sub>	18.2	A
Avalanche Energy, L = 1mH		Eas	165	mJ

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	2.62	W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	57.8	°C/W	
Total Power Dissipation (Note 7) $T_{C} = +25^{\circ}C$		PD	65.2	W
Thermal Resistance, Junction to Case (Note 7)		R <sub>ejc</sub>	2.3	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

#### Electrical Characteristics (@T<sub>J</sub> = +25°C, unless otherwise specified.)

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	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	1			1		T	
Drain-Source Breakdown Voltage	BVDSS	40		—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	—		1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	—		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	1.5	2.5	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	D	_	2.3	3.0		$V_{GS} = 10V, I_{D} = 20A$	
Static Drain-Source On-Resistance	RDS(ON)	_	3.4	5.0	<b>m</b> 0	$V_{GS} = 5V, I_D = 15A$	
Statia Drain Source On Desistence (T. 1759C) (Nete 0)	Descent		_	6.0	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance $(T_J = +175^{\circ}C)$ (Note 9)	RDS(ON)	_	_	9.0		V <sub>GS</sub> = 5V, I <sub>D</sub> = 15A	
Diode Forward Voltage	V <sub>SD</sub>	—	0.8	1.0	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	2798	-		$V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss		904	—	pF		
Reverse Transfer Capacitance	Crss	_	88				
Gate Resistance	Rg		2.44	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	—	40.1	—		$V_{DS} = 20V, I_D = 20A, V_{GS} = 10V$	
Gate-Source Charge	Qgs	—	5.2	—	nC		
Gate-Drain Charge	Qgd	—	8.8	—		$v_{GS} = 10v$	
Turn-On Delay Time	td(on)	—	5.16	—		$V_{DD} = 20V, V_{GS} = 10V,$ $R_G = 1.6\Omega, I_D = 20A$	
Turn-On Rise Time	tR	_	10.7	_			
Turn-Off Delay Time	tD(OFF)	_	24.6	—	ns		
Turn-Off Fall Time	tF	_	12.4	—			
Body Diode Reverse Recovery Time	trr	_	32.6	—	ns		
Body Diode Reverse Recovery Charge	QRR	_	26.6	—	nC	IF = 15A, di/dt = 100A/µs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.

10. Package limit.



#### DMTH43M8LFGQ

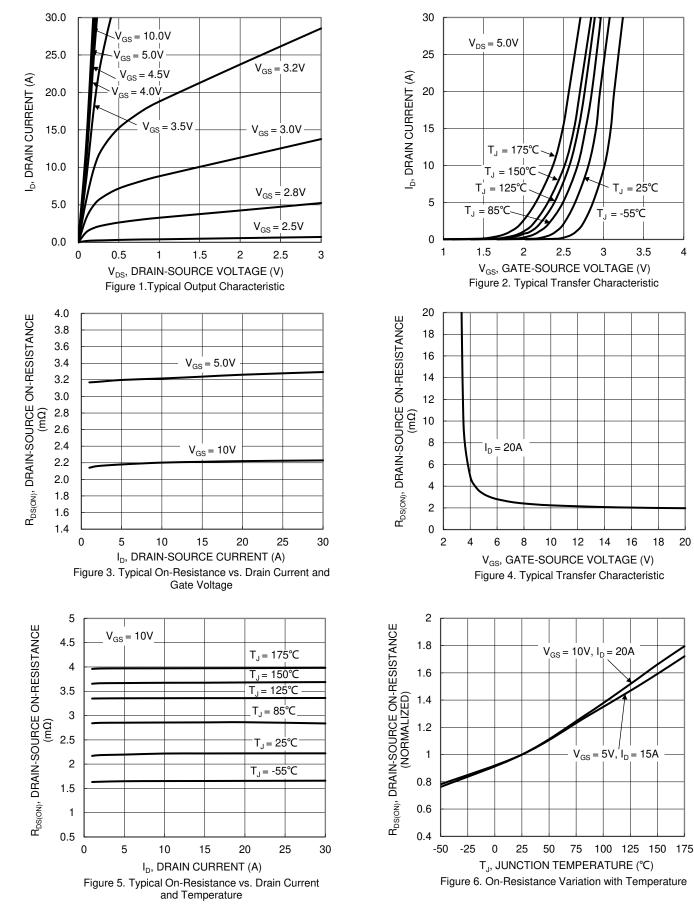
T<sub>J</sub> = 25<sup>°</sup>C

3.5

4

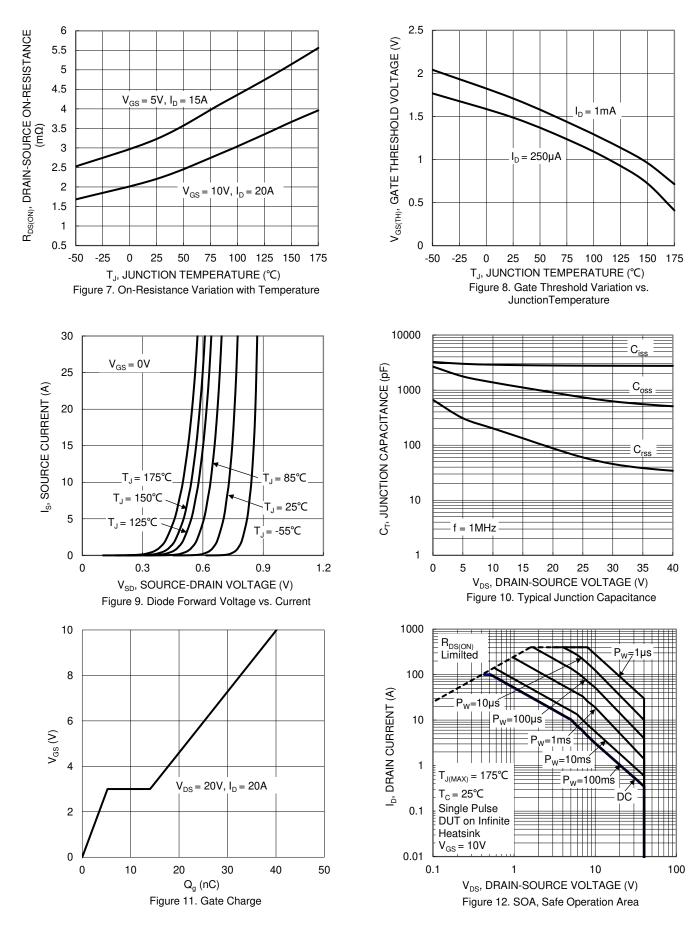
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16 18 20





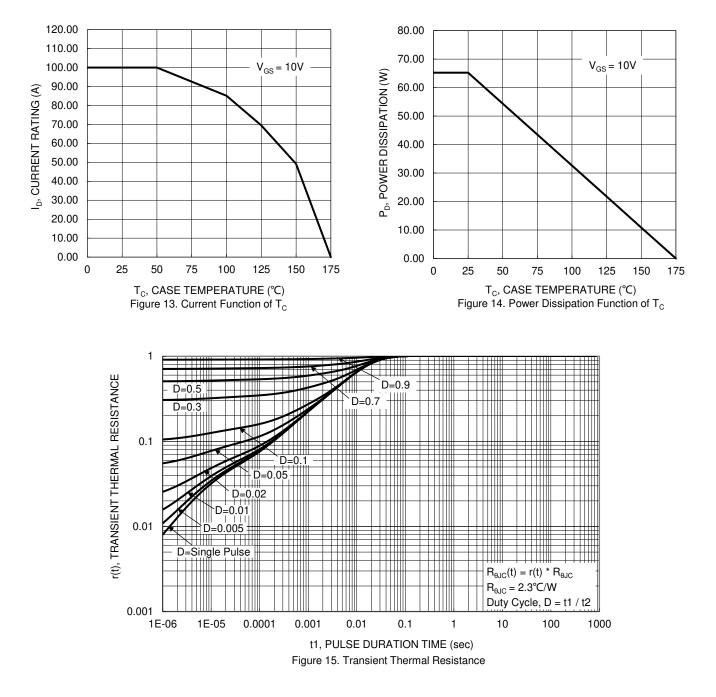
#### DMTH43M8LFGQ



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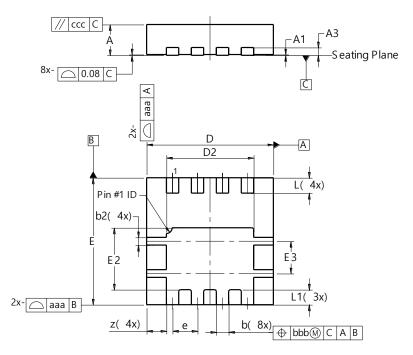
#### DMTH43M8LFGQ





# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

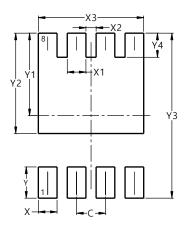


			_			
PowerDI3333-8						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	-	-	0.203			
b	0.27	0.37	0.32			
b2	-	-	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
Е	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
E3	0.79	0.89	0.84			
е	-	-	0.65			
L	0.35	0.45	0.40			
L1	-	-	0.39			
z	-	-	0.515			
aaa	0.25					
bbb	0.10					
CCC	0.10					
All Dimensions in mm						

#### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8



Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
X3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		

# PowerDI3333-8



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